

TBM808P

SINGLE PHASE 8.0AMPS. LOW VF BRIDGE RECTIFIERS

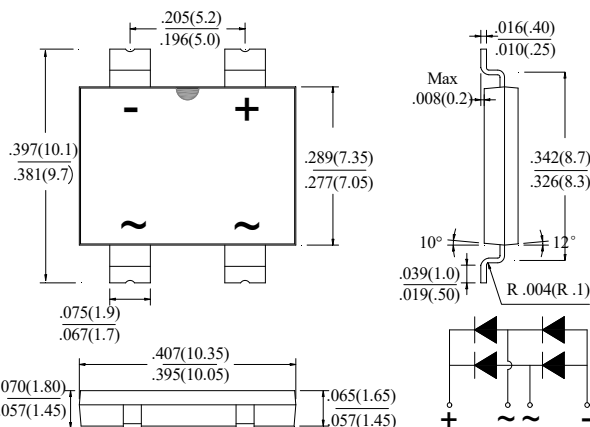
FEATURE

- . Surface mount bridge, small package;
- . Ideal for printed circuit board.
- . Reliable low cost construction utilizing molded plastic technique.
- . High surge current capability.
- . High temperature soldering guaranteed: 260°C/10 seconds at terminals.

MECHANICAL DATA

- . Case Material: “Green” Molding compound, UL flammability classification rating 94V-0, “Free halogen”
- . Moisture sensitivity level:level 2a,per J-STD-020
- . Polarity:Polarity as marked on the body
- . Weight: 0.415g (approximately)

TBM



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz,resistive or inductive load. For capacitive load, derate current by 20%

Type Number	SYM BOL	TBM808P			units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	800			V
Maximum RMS Voltage	V_{RMS}	560			V
Maximum DC blocking Voltage	V_{DC}	800			V
Maximum Average Forward rectified Current	$I_{F(AV)}$	8.0			A
Peak Forward Surge Current @ $T_J=25^{\circ}C$	I_{FSM}	200			A
8.3ms single half sine-wave @ $T_J=125^{\circ}C$		150			
Peak Forward Surge Current @ $T_J=25^{\circ}C$		400			
1.0ms single half sine-wave @ $T_J=125^{\circ}C$		300			
Maximum Forward Voltage @ 8.0A DC	V_F	Typ 0.90	Max 0.95		V
Drop per element @ 4.0A DC		Typ 0.83	Max 0.88		
Maximum DC Reverse Current @ $T_J=25^{\circ}C$	I_R	5.0			μA
at rated DC blocking voltage @ $T_J=125^{\circ}C$		200.0			
I^2t Rating for Fusing ($t < 8.3ms$)	I^2t	166			A^2Sec
Maximum Reverse Recovery Time (Note 1)	t_{rr}	500			nS
Typical Junction Capacitance Per Leg (Note2)	C_J	140			pF
Typical Thermal Resistance (without Heatsink)	R_{JA}	R_{JA}	R_{JL}	R_{JC}	$^{\circ}C / W$
		55	8	7	
Typical Thermal Resistance (Note3)		10	6	2	
Storage Temperature	T_{STG}	-55 to +150			$^{\circ}C$
Operating Junction Temperature	T_J	-55 to +150			$^{\circ}C$

Note:

1. Test Conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$
2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
3. Thermal resistance junction to case, lead and ambient in accordance with JESD-51. Unit mounted on 15mm x 12mm x 1.6mm AL Pad attached on 100mm x 100mm x 30mm copper plate

Ratings and Characteristics Curves

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

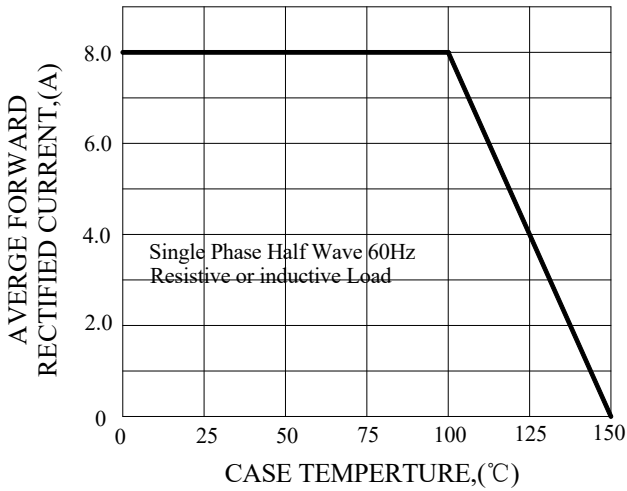


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

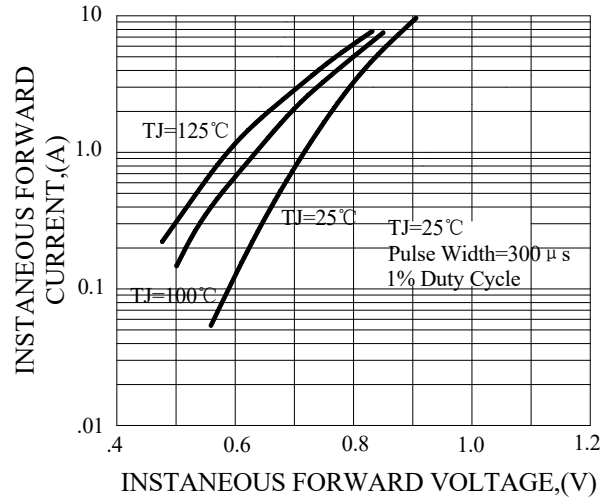


FIG.3-MAXIMUN NON-REPETITIVE FORWARD SURGE CURRENT

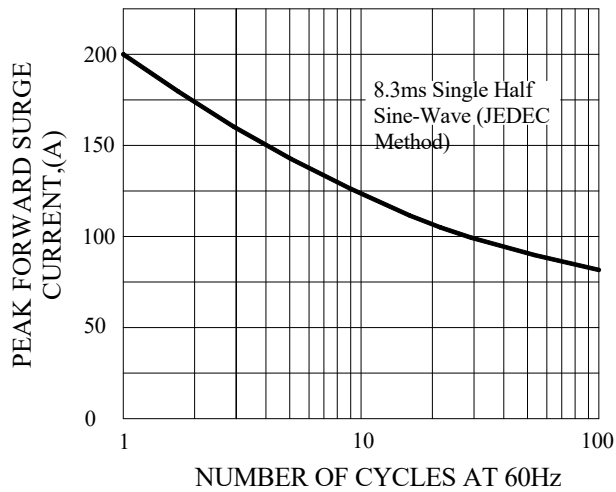


FIG.4-TYPIAL JUNCTION CAPACITANCE

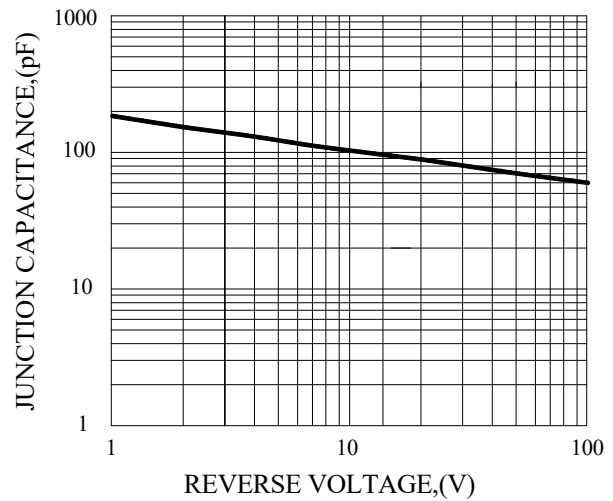


FIG.5-TYPICAL REVERSE CHARACTERISTICS

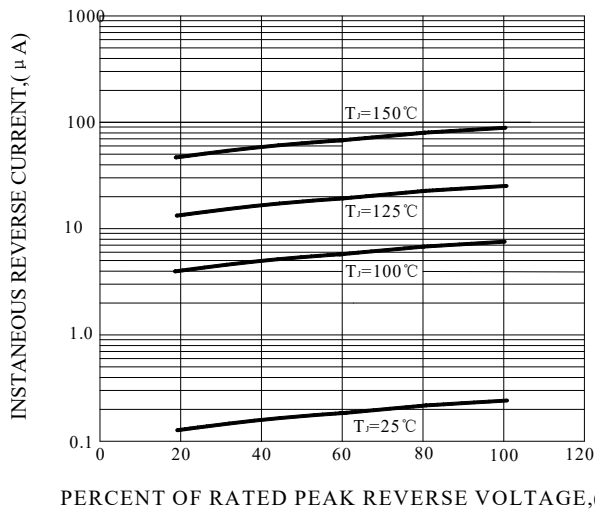
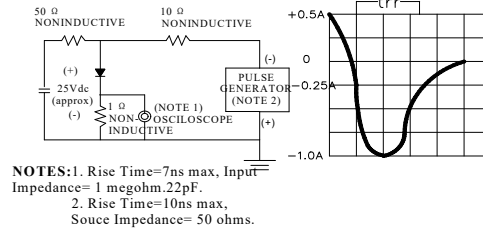
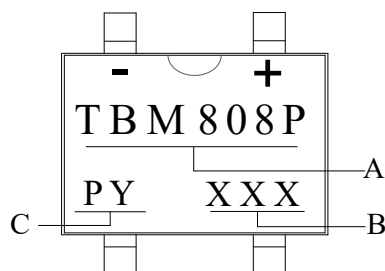


FIG.6-TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



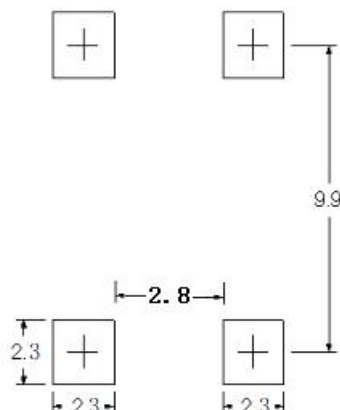
Marking、 Pad Layout 、 MOQ and packaging illustration

1、 Marking



SYMBOL	Explanation
A	Product Name
B	Date Code
C	Trademark

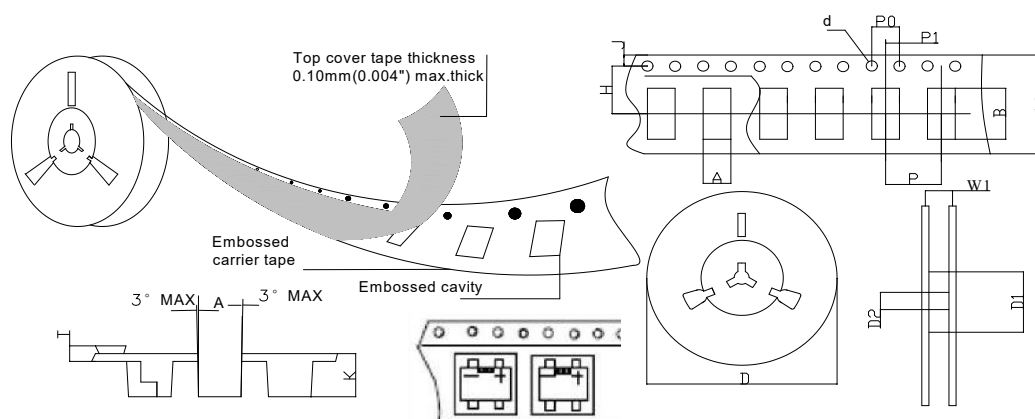
2、 Suggested Pad Layout (mm)



3、 MOQ

1500pcs / Tape & Reel

4、 Packaging



SPECIFICATIONS mm(inch)		PACKAGE	SPECIFICATIONS mm(inch)		PACKAGE
ITEM	SYM BOL	TBM	ITEM	SYM BOL	TBM
Carrier width	A	10.5(0.413)Max	Carrier depth	K	2.25(0.088)Typ
Carrier length	B	11.0(0.433)Max	Punch hole pitch	P	16.00(0.630)Typ
Sprocket hole	d	ø1.6(0.063)Typ	Sprocket hole pitch	P0	4.00(0.157)Typ
Reel outer diameter	D	330.0(13.0)Typ	Embossment center	P1	2.00(0.079)Typ
Reel inner diameter	D1	75.0(2.953)Min	Overall tape thickness	T	0.30(0.012)Typ
Feed hole diameter	D2	13.0(0.512)Typ	Tape width	W	24.0(0.945)Typ
Sprocket hole position	J	1.75(0.069)Typ	Reel width	W1	25.5(1.004)Min
Punch hole position	H	11.50(0.452)Typ			